

Low Power, High Speed Operational Amplifier

F€ATUR€S

Gain-Bandwidth Product: 50MHz

Unity-Gain Stable
 Slew Rate: 165V/µs
 Output Current: ±20mA
 Low Supply Current: 12mA
 High Open-Loop Gain: 7.5V/mV

Low Cost

Single Supply 5V Operation

Industry Standard Pinout

Output Shutdown

APPLICATIONS

- Video Cable Drivers
- Video Signal Processing
- Fast Peak Detectors
- Fast Integrators
- Video Cable Drivers
- Pulse Amplifiers

DESCRIPTION

The LT $^{\circ}$ 1195 is a video operational amplifier optimized for operation on single 5V and \pm 5V supplies. Unlike many high speed amplifiers, the LT1195 features high open-loop gain, over 75dB, and the ability to drive heavy loads to a full power bandwidth of 8.5 MHz at 6V_{P-P}. The LT1195 has a unity-gain stable bandwidth of 50MHz, a 60° phase margin and consumes only 12mA of supply current, making it extremely easy to use.

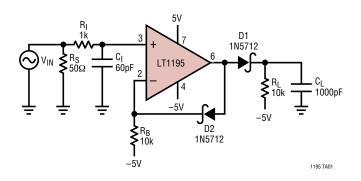
Because the LT1195 is a true operational amplifier, it is an ideal choice for wideband signal conditioning, fast integrators, peak detectors, active filters, and applications requiring speed, accuracy, and low cost.

The LT1195 is a low power version of the popular LT1190, and is available in 8-pin miniDIPs and SO packages with standard pinouts. The normally unused Pin 5 is used for a shutdown feature that shuts off the output and reduces power dissipation to a mere 15mW.

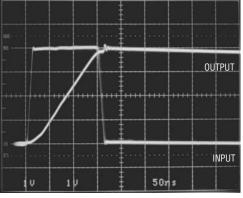
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TYPICAL APPLICATION

Fast Pulse Detector



Pulse Detector Response

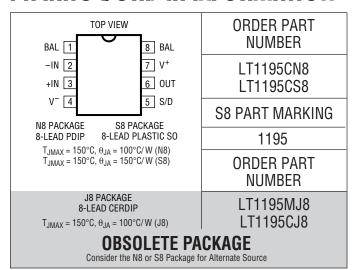


1195TA02

ABSOLUTE MAXIMUM RATINGS

(Note 1)
Total Supply Voltage (V+ to V ⁻) 18V
Differential Input Voltage±6V
Input Voltage ±V _S
Output Short-Circuit Duration (Note 2) Continuous
Operating Temperature Range
LT1195M (OBSOLETE)55°C to 125°C
LT1195C0°C to 70°C
Junction Temperature (Note 3)
Plastic Package (CN8, CS8) 150°C
Ceramic Package (CJ8, MJ8) (OBSOLETE) 175°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec)300°C

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

±5V ELECTRICAL CHARACTERISTICS

 $V_S = \pm 5V$, $C_L \le 10 pF$, Pin 5 open circuit, unless otherwise noted.

					LT1195M/C		
SYMBOL	PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS
V_{0S}	Input Offset Voltag	je	J8, N8 Package		3.0	8.0	mV
			S8 Package		3.0	10.0	mV
I _{OS}	Input Offset Currer	nt			0.2	1.0	μА
IB	Input Bias Current				±0.5	±2.0	μА
e _n	Input Noise Voltag	е	$f_0 = 10kHz$		70		nV√Hz
in	Input Noise Currer	nt	$f_0 = 10kHz$		2		pA√Hz
R _{IN}	Input Resistance	Differential Mode			230		kΩ
		Common Mode			20		MΩ
C _{IN}	Input Capacitance		$A_V = 1$		2.2		pF
	Input Voltage Ranç	ge	(Note 4)	-2.5		3.5	V
CMRR	Common Mode Re	ejection Ratio	$V_{CM} = -2.5 \text{ to } 3.5 \text{V}$	60	85		dB
PSRR	Power Supply Reje	ection Ratio	$V_S = \pm 2.375 V \text{ to } \pm 8 V$	60	85		dB
A _{VOL}	Large-Signal Volta	ge Gain	$R_L = 1k$, $V_{OUT} = \pm 3V$	2.0	7.5		V/mV
			$R_L = 150\Omega$, $V_{OUT} = \pm 3V$	0.5	1.5		V/mV
			$V_S = \pm 8V, R_L = 1k, V_{OUT} = \pm 5V$		11.0		V/mV
V_{OUT}	Output Voltage Sw	ring	$V_S = \pm 5V, R_L = 1k$	±3.8	±4.0		V
			$V_S = \pm 8V$, $R_L = 1k$	±6.7	±7.0		V
SR	Slew Rate		$A_V = -1$, $R_L = 1k$ (Note 5, 10)	110	165		V/μs
FPBW	Full Power Bandwi	dth	$V_{OUT} = 6V_{P-P}$ (Note 6)		8.75		MHz
GBW	Gain-Bandwidth Pr	roduct			50		MHz
t_{r1}, t_{f1}	Rise Time, Fall Tim	ne	$A_V = 50$, $V_{OUT} = \pm 1.5V$, 20% to 80% (Note 10)	125	170	285	ns
t_{r2}, t_{f2}	Rise Time, Fall Tim	ne	$A_V = 1$, $V_{OUT} = \pm 125$ mV, 10% to 90%		3.4		ns
t _{PD}	Propagation Delay		$A_V = 1$, $V_{OUT} = \pm 125$ mV, 50% to 50%		2.5		ns
	Overshoot		$A_V = 1$, $V_{OUT} = \pm 125 \text{mV}$		22		%
t _S	Settling Time		3V Step, 0.1% (Note 7)		220		ns
Diff A _V	Differential Gain		$R_L = 150\Omega$, $A_V = 2$ (Note 8)		1.25		%
Diff Ph	Differential Phase		$R_L = 150\Omega$, $A_V = 2$ (Note 8)		0.86		DEG _{P-P}
	•						1195fa

 $T_A = 25^{\circ}C$

\pm 5V ELECTRICAL CHARACTERISTICS $T_A = 25$ °C

 V_S = $\pm 5V,~C_L \leq 10 pF,~Pin~5~open~circuit,~unless~otherwise~noted.$

				LT1195M/C		
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
I_S	Supply Current			12	16	mA
	Shutdown Supply Current	Pin 5 at V ⁻		0.8	1.5	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V ⁻		5	25	μА
t_{ON}	Turn-On Time	Pin 5 from V ⁻ to Ground, R _L = 1k		160		ns
t _{OFF}	Turn-Off Time	Pin 5 from Ground to V ⁻ , R _L = 1k		700		ns

5V ELECTRICAL CHARACTERISTICS $T_A = 25$ °C

 V_S^+ = 5V, $V_S^-,$ = 0V, V_{CM} = 2.5V, $C_L \le$ 10pF, Pin 5 open circuit, unless otherwise noted.

					LT1195M/	C	
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	J8, N8 Package S8 Package			3.0 3.0	9.0 11.0	mV mV
I _{OS}	Input Offset Current				0.2	1.0	μΑ
I _B	Input Bias Current				±0.5	±2.0	μΑ
	Input Voltage Range	(Note 4)		2.0		3.5	V
CMRR	Common Mode Rejection Ratio	V _{CM} = 2V to 3.5V		60	85		dB
A _{VOL}	Large-Signal Voltage Gain	$R_L = 150\Omega$ to Ground, V_{OU}	_r = 1V to 3V	0.5	3.0		V/mV
V _{OUT}	Output Voltage Swing	$R_L = 150\Omega$ to Ground	V _{OUT} High	3.5	3.8		V
			V _{OUT} Low		0.25	0.4	V
SR	Slew Rate	$A_V = -1$, $V_{OUT} = 1V$ to $3V$	•		140		V/µs
GBW	Gain-Bandwidth Product				45		MHz
Is	Supply Current				11	15	mA
	Shutdown Supply Current	Pin 5 at V ⁻			0.8	1.5	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V ⁻			5	25	μА

$\pm 5V$ ELECTRICAL CHARACTERISTICS $-55^{\circ}C \le T_{A} \le 125^{\circ}C$, (Note 11)

 $V_S = \pm 5V$, Pin 5 open circuit, unless otherwise noted.

				LT1195M		
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$\overline{V_{OS}}$	Input Offset Voltage			3.0	15.0	mV
$\Delta V_{OS}/\Delta T$	Input V _{OS} Drift			17		μV/°C
I _{OS}	Input Offset Current			0.2	2.0	μΑ
I _B	Input Bias Current			±0.5	±2.5	μΑ
CMRR	Common Mode Rejection Ratio	$V_{CM} = -2.5V \text{ to } 3.5V$	55	85		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.375V \text{ to } \pm 8V$	55	80		dB
A _{VOL}	Large-Signal Voltage Gain	$R_L = 1k, V_{OUT} = \pm 3V$ $R_L = 150\Omega, V_{OUT} = \pm 3V$	1.50 0.25	5.0 0.8		V/mV V/mV
V_{OUT}	Output Voltage Swing	R _L = 1k	±3.7	±3.9		V
Is	Supply Current			12	18	mA
	Shutdown Supply Current	Pin 5 at V ⁻ , (Note 9)		0.8	2.5	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V ⁻		5	25	μΑ



±5V ELECTRICAL CHARACTERISTICS 0°C ≤ TA ≤ 70°C

 $V_S = \pm 5V$, Pin 5 open circuit, unless otherwise noted.

				LT1195C			
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
$\overline{V_{0S}}$	Input Offset Voltage	J8, N8 Package		3.0	10.0	mV	
		S8 Package		3.0	15.0	mV	
$\Delta V_{OS}/\Delta T$	Input V _{OS} Drift			12		μV/°C	
I _{OS}	Input Offset Current			0.2	1.7	μΑ	
I _B	Input Bias Current			±0.5	±2.5	μΑ	
CMRR	Common Mode Rejection Ratio	$V_{CM} = -2.5V \text{ to } 3.5V$	60	85		dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.375V \text{ to } \pm 5V$	60	90		dB	
A _{VOL}	Large-Signal Voltage Gain	$R_L = 1k$, $V_{OUT} = \pm 3V$	2.0	7.5		V/mV	
		$R_L = 150\Omega, V_{OUT} = \pm 3V$	0.3	1.5		V/mV	
V_{OUT}	Output Voltage Swing	R _L = 1k	±3.7	±3.9		V	
Is	Supply Current			12	17	mA	
	Shutdown Supply Current	Pin 5 at V ⁻ (Note 9)		0.9	2.0	mA	
I _{S/D}	Shutdown Pin Current	Pin 5 at V ⁻		5	25	μА	

5V ELECTRICAL CHARACTERISTICS $0^{\circ}C \le T_A \le 70^{\circ}C$

 $V_S^+ = 5V$, $V_S^- = 0V$, Pin 5 open circuit, unless otherwise noted.

					LT1195C		
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{0S}	Input Offset Voltage	J8, N8 Package S8 Package			1.0 1.0	10.0 15.0	mV mV
$\Delta V_{OS}/\Delta T$	Input V _{OS} Drift				15		μV/°C
I _{OS}	Input Offset Current				0.2	1.7	μА
I _B	Input Bias Current				±0.5	±2.5	μА
	Input Voltage Range	(Note 4)		2.0		3.5	V
CMRR	Common Mode Rejection Ratio	V _{CM} = 2V to 3.5V		60	85		dB
$\overline{V_{OUT}}$	Output Voltage Swing	$R_L = 150\Omega$ to Ground	V _{OUT} High	3.5	3.75		V
			V _{OUT} Low		0.15	0.4	V
Is	Supply Current		•		12	16	mA
	Shutdown Supply Current	Pin 5 at V ⁻ (Note 9)			0.9	2.0	mA
I _{S/D}	Shutdown Pin Current	Pin 5 at V ⁻			5	25	μА

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum when the output is shorted continuously.

Note 3: T_J is calculated from the ambient temperature T_A and power dissipation P_D according to the following formats:

$$\begin{split} LT1195MJ8/LT1195CJ8: & T_J = T_A + (P_D \bullet 100^{\circ}C/W) \\ LT1195N: & T_J = T_A + (P_D \bullet 100^{\circ}C/W) \\ LT1195CS: & T_J = T_A + (P_D \bullet 150^{\circ}C/W) \end{split}$$

Note 4: Exceeding the input common mode range may cause the output to invert.

Note 5: Slew rate is measured between ±1V on the output, with ±3V input step.

Note 6: Full power bandwidth is calculated from the slew rate measurement: FPBW = $SR/2\pi V_P$.

Note 7: Settling time measurement techniques are shown in "Take the Guesswork Out of Settling Time Measurements," EDN, September 19, 1985.

Note 8: NTSC (3.58MHz). For $R_L = 1k$, Diff $A_V = 0.3\%$, Diff $Ph = 0.35^\circ$.

Note 9: See Applications Information section for shutdown at elevated temperatures. Do not operate the shutdown above $T_J > 125\,^{\circ}C$.

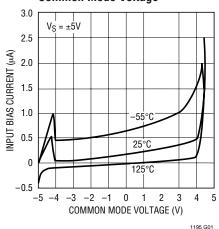
Note 10: AC parameters are 100% tested on the ceramic and plastic DIP packaged parts (J8 and N8 suffix) and are sample tested on every lot of the SO packaged parts (S8 suffix).

Note 11: Do not operate at $A_V < 2$ for $T_A < 0$ °C.

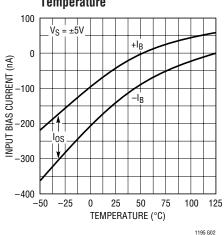
TECHNOLOGY TECHNOLOGY

TYPICAL PERFORMANCE CHARACTERISTICS

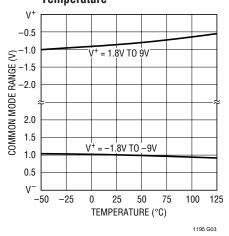
Input Bias Current vs Common Mode Voltage



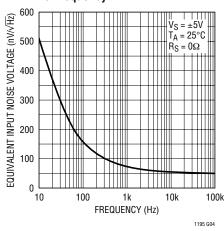
Input Bias Current vs Temperature



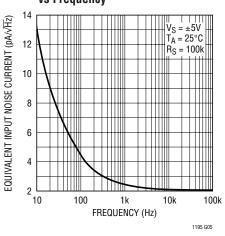
Common Mode Voltage vs Temperature



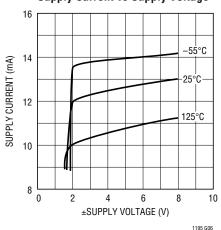
Equivalent Input Noise Voltage vs Frequency



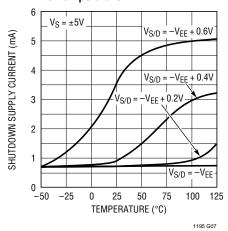
Equivalent Input Noise Current vs Frequency



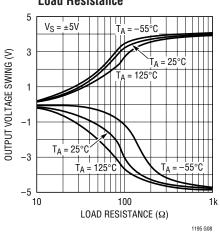
Supply Current vs Supply Voltage



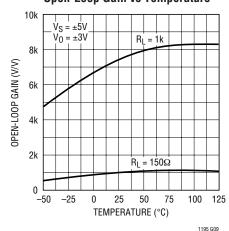
Shutdown Supply Current vs Temperature



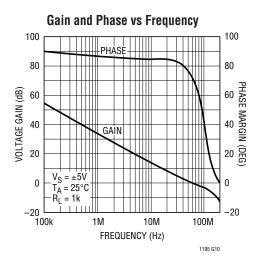
Output Voltage Swing vs Load Resistance

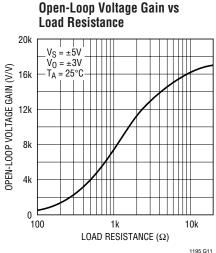


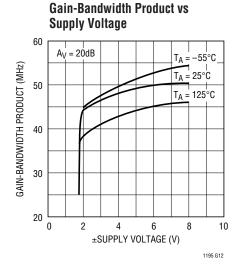
Open-Loop Gain vs Temperature



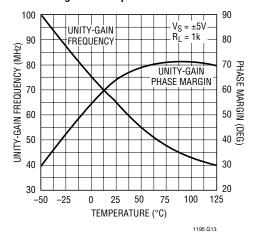
TYPICAL PERFORMANCE CHARACTERISTICS



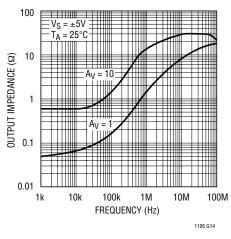




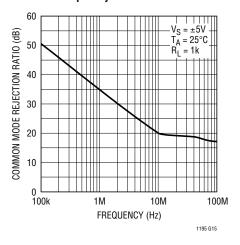
Unity-Gain Frequency and Phase Margin vs Temperature



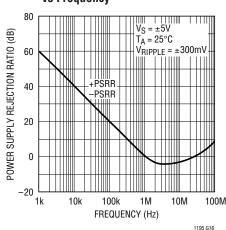




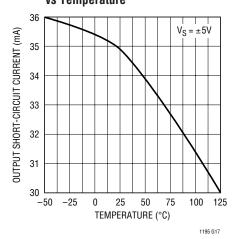
Common Mode Rejection Ratio vs Frequency



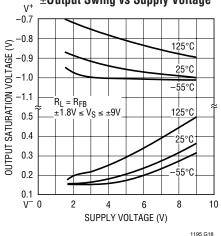
Power Supply Rejection Ratio vs Frequency



Output Short-Circuit Current vs Temperature





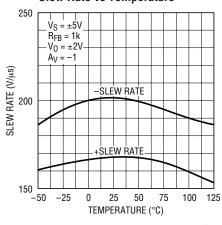




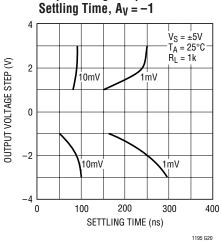


TYPICAL PERFORMANCE CHARACTERISTICS

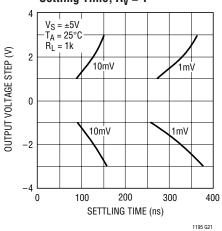
Slew Rate vs Temperature



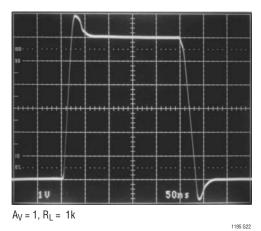
Output Voltage Step vs Settling Time. Av = -1



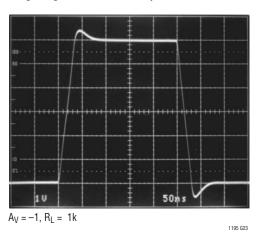
Output Voltage Step vs Settling Time, $A_V = 1$



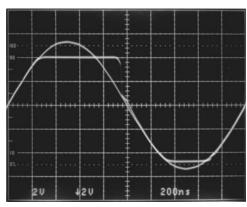
Large-Signal Transient Response



Large-Signal Transient Response



Overload Recovery



 $A_V = 1, V_{1N} = 11V_{P-P}$

1195 G24

3 + 7 LT1195 6

INPUT OFFSET VOLTAGE CAN BE ADJUSTED OVER A ±150mV RANGE WITH A 1k to 10k POTENTIOMETER.

1195 G25



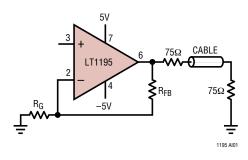
Power Supply Bypassing

The LT1195 is quite tolerant of power supply bypassing. In some applications a $0.1\mu F$ ceramic disc capacitor placed 0.5 inches from the ampifier is all that is required. In applications requiring good settling time, it is important to use multiple bypass capacitors. A $0.1\mu F$ ceramic disc in parallel with a $4.7\mu F$ tantalum is recommended.

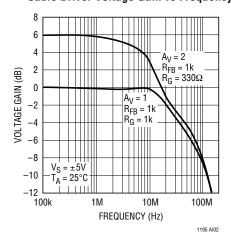
Cable Terminations

The LT1195 operational amplifier has been optimized as a low cost video cable driver. The ± 20 mA guaranteed output current enables the LT1195 to easily deliver $6V_{P-P}$ into 150Ω , while operating on $\pm 5V$ supplies.

Double-Terminated Cable Driver



Cable Driver Voltage Gain vs Frequency



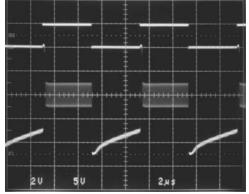
When driving a cable it is important to terminate the cable to avoid unwanted reflections. This can be done in one of two ways: single termination or double termination. With single termination, the cable must be terminated at the

receiving end (75Ω) to ground) to absorb unwanted energy. The best performance can be obtained by double termination (75Ω) in series with the output of the amplifier, and 75Ω to ground at the other end of the cable). This termination is preferred because reflected energy is absorbed at each end of the cable. When using the double termination technique it is important to note that the signal is attenuated by a factor of 2, or 6dB. This can be compensated for by taking a gain of 2, or 6dB in the amplifier.

Using the Shutdown Feature

The LT1195 has a unique feature that allows the amplifier to be shut down for conserving power, or for multiplexing several amplifiers onto a common cable. The amplifier will shutdown by taking Pin 5 to V $^-$. In shutdown, the amplifier dissipates 15mW while maintaining a true high impedance output state of 15k in parallel with the feedback resistors. The amplifiers must be used in a noninverting configuration for MUX applications. In inverting configurations the input signal is fed to the output through the feedback components. The following scope photos show that with very high $R_{\rm L}$, the output is truly high impedance; the output slowly decays toward ground. Additionally, when the output is loaded with as little as 1k the amplifier shuts off in 700ns. This shutoff can be under the control of HC CMOS operating between 0V and -5V.

Output Shutdown



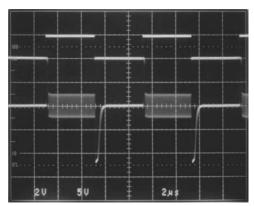
1MHz SINE WAVE GATED OFF WITH SHUTDOWN PIN $A_V = 1$, $R_L = SCOPE$ PROBE

1195 AI03





Output Shutdown



1MHz SINE WAVE GATED OFF WITH SHUTDOWN PIN

 $A_V = 1$, $R_L = 1k$

1195 Al04

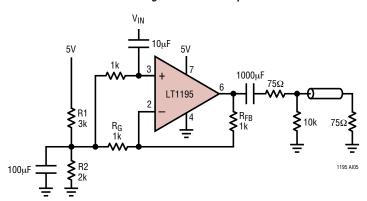
Detecting Pulses

The front page shows a circuit for detecting very fast pulses. In this open-loop design, the detector diode is D1 and a level shifting or compensating diode is D2. A load resistor R_L is connected to -5V, and an identical bias resistor R_B is used to bias the compensating diode. Equal value resistors ensure that the diode drops are equal. A very fast pulse will exceed the amplifier slew rate and cause a long overload recovery time. Some amount of dV/dt limiting on the input can help this overload condition, however too much will delay the response. Also shown is the response to a $4V_{P-P}$ input that is 150ns wide. The maximum output slew rate in the photo is $30V/\mu s$. This rate is set by the 30mA current limit driving 1000pF.

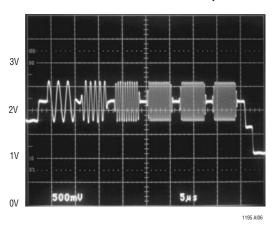
Operation on Single 5V Supply

The LT1195 has been optimized for a single 5V supply. This circuit amplifies standard composite video ($1V_{P-P}$ including sync) by 2 and drives a double-terminated 75Ω cable. Resistors R1 and R2 bias the amplifier at 2V, allowing the sync pulses to stay within the common mode range of the amplifier. Large coupling capacitors are required to pass the low frequency sidebands of the composite signal. A multiburst response and vector plot standard color burst are shown.

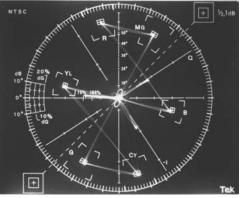
Single 5V Video Amplifier



Video Multiburst at Pin 6 of Amplifier



Vector Plot of Standard Color Burst

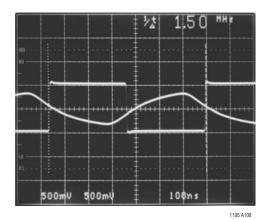


1195 AI0

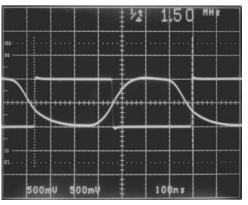
Send Color Video Over Twisted-Pair

With an LT1195 it is possible to send and receive color composite video signals more than 1000 feet on a low cost twisted-pair. A bidirectional "video bus" consists of the LT1195 op amp and the LT1187 video difference amplifier. A pair of LT1195s at TRANSMIT 1, is used to generate differential signals to drive the line which is back-terminated in its characteristic impedance. The LT1187 twisted-pair receiver, converts signals from differential to single-ended. Topology of the LT1187 provides for cable compensation at the amplifier's feedback node as shown. In this case, 1000 feet of twisted-pair is compensated with 1000pF and 50Ω to boost the 3dB bandwidth of the system from 750kHz to 4MHz. This bandwidth is adequate to pass a 3.58MHz chrome subcarrier and the 4.5MHz sound subcarrier. Attenuation in the cable can be compensated by lowering the gain set resistor R_G. At TRANSMIT 2, another pair of LT1195s serve the dual function to provide cable termination via low output impedance and generate differential signals for TRANSMIT 2. Cable termination is made up of 15Ω and 33Ω attentuators to reduce the differential input signal to the LT1187. Maximum input signal for the LT1187 is 760mV_{P-P}.

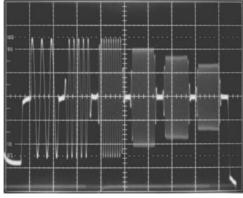
1.5MHz Square Wave Input and Unequalized Response Through 1000 Feet of Twisted-Pair



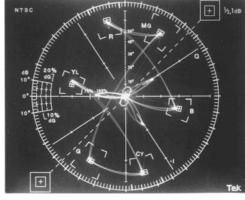
1.5MHz Square Wave Input and Equalized Response Through 1000 Feet of Twisted-Pair



Multiburst Pattern Passed Through 1000 Feet of Twisted-Pair

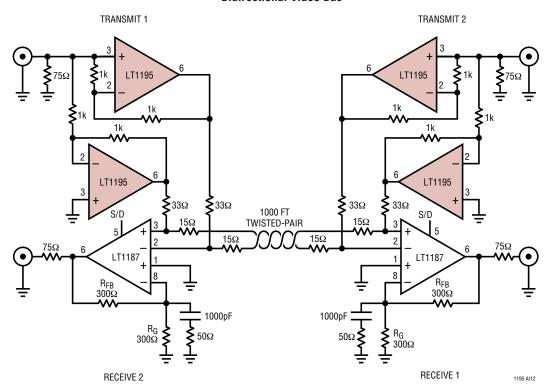


Vector Plot of Standard Color Burst Through 1000 Feet of Twisted-Pair

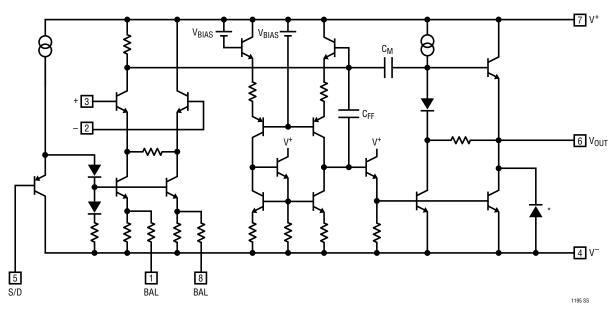




Bidirectional Video Bus



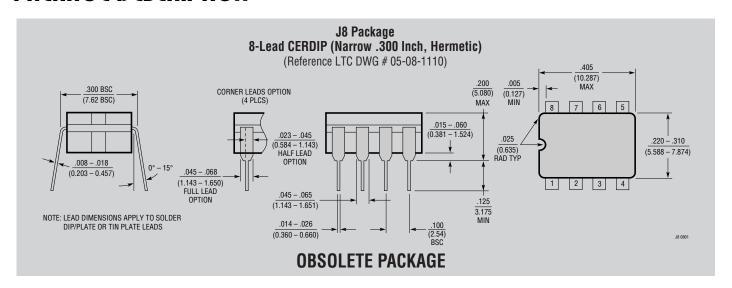
SIMPLIFIED SCHEMATIC



* SUBSTRATE DIODE, DO NOT FORWARD BIAS

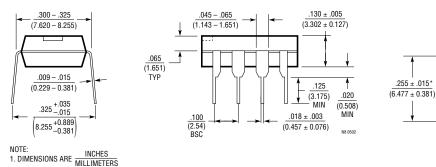


PACKAGE DESCRIPTION



N8 Package 8-Lead PDIP (Narrow .300 Inch)

(Reference LTC DWG # 05-08-1510)



^{*}THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch)

(Reference LTC DWG # 05-08-1610) .045 ±.005 .050 BSC $(\overline{4.801 - 5.004})$ NOTE 3 .245 MIN .160 ±.005 .150 - .157 (3.810 - 3.988) .228 - .244 (5.791 - 6.197) NOTE 3 N/2 .030 ±.005 -TYP RECOMMENDED SOLDER PAD LAYOUT 4 INCHES 1. DIMENSIONS IN (MILLIMETERS) 2. DRAWING NOT TO SCALE
3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. .053 - .069 $(\overline{1.346 - 1.752})$ MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006" (0.15mm) (0.254 - 0.508).004 - .010(0.101 - 0.254)010. - 800 (0.203 - 0.254)0°-8° TYP .050 (1.270) BSC .016 - .050

(0.406 - 1.270)

(0.355 – 0.483) TYP

.400*

(10.160) MAX

2 3

6 7

4